



SBR8A45SP5

8A SBR® **SUPER BARRIER RECTIFIER POWERDI**®

Features

- Designed as Bypass Diodes for Solar Panels
- Selectively Rated for +200°C Maximum Junction Temperature for High Thermal Reliability
- Patented Super Barrier Rectifier Technology
- Low Forward Voltage Drop
- **Excellent High Temperature Stability**
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: POWERDI®5
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.093 grams (Approximate)

POWERDI®5



Top View



Bottom View



Note: Pins Left & Right must be electrically connected at the printed circuit board.

Ordering Information (Note 4)

Part Number	Case	Packaging
SBR8A45SP5-13	POWERDI [®] 5	5.000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

POWERDI®5



S8A45S = Product Type Marking Code D11 = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 15 for 2015) WW = Week Code (01 ~ 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	45	٧
Average Rectified Output Current	lo	8	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	180	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Typical Thermal Resistance Junction to Lead		$R_{\theta JL}$	3	°C/W
Typical Thermal Resistance Junction to Case (Note 5)		$R_{\theta JC}$	8	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)		$R_{\theta JA}$	102	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)		$R_{\theta JA}$	60	°C/W
	V _R ≤ 80% V _{RRM}		-65 to +150	
Operating Temperature Range	$V_R \le 50\% V_{RRM}$	T_J	≤180	°C
	DC Forward Mode		≤200	
Storage Temperature Range		T_{STG}	-65 to +175	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	V _F	-	-	0.60	l V	I _F = 8A, T _J = +25°C
		-	0.52	0.57		$I_F = 8A, T_J = +125$ °C
Leakage Current (Note 7)	IR	-	0.03	0.30	mA	V _R = 45V, T _J = +25°C
Leanage Current (NOIE 7)		ı	10	75		$V_R = 45V, T_J = +125^{\circ}C$

Notes:

- 5. FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com.
- 6. Polymide PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com.
- 7. Short duration pulse test used to minimize self-heating effect.



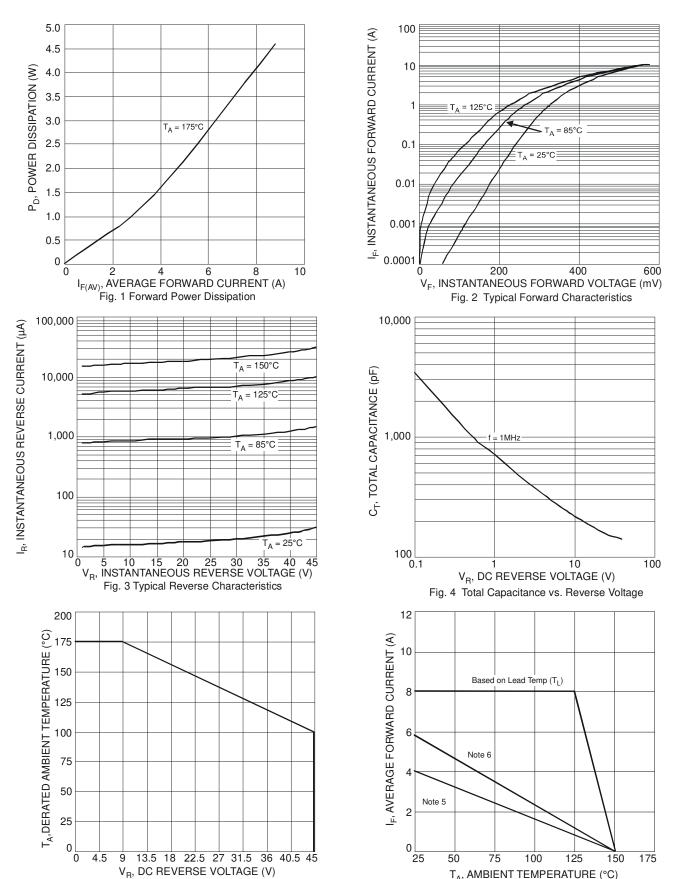


Fig. 5 Operating Temperature Derating

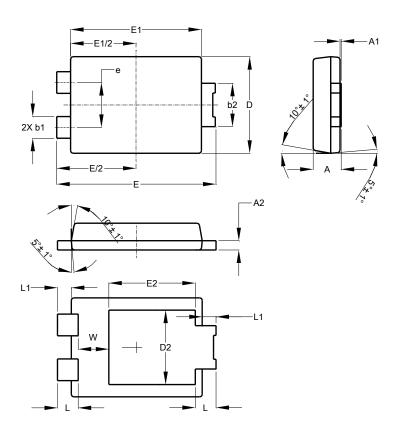
T_A, AMBIENT TEMPERATURE (°C)

Fig. 6 Forward Current Derating Curve



Package Outline Dimensions

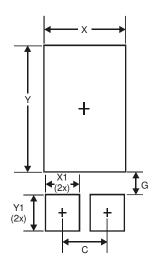
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI [®] 5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2	-	-	3.054		
Е	6.40	6.60	6.504		
е	-	-	1.84		
E1	5.30	5.45	5.37		
E2	-	-	3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Υ	4.860
Y1	1.400



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